

1. General description

Planar passivated high commutation three quadrant triac in a SOT78D (TO-220AB) internally insulated plastic package intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. This "series B" triac will commutate the full RMS current at the maximum rated junction temperature without the aid of a snubber. This device has high T_i operating capability and an internally isolated mounting base.

2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High surge capability
- High T_{i(max)}
- Isolated mounting base with 2500 V (RMS) isolation
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- Electronic thermostats (heating and cooling)
- High power motor controls
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | |
|---------------------|--|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u> | - | - | 140 | A |
| Tj | junction temperature | | - | - | 150 | °C |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 116 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 12 | A |





BTA412Y-600B

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| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|-----------------|----------------------|--|-----|-----|-----|------|
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | 2 | - | 50 | mA |
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{2}$ | 2 | - | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | 2 | - | 50 | mA |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2-71 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | |
| mb | n.c. | mounting base; isolated | | |
| | | | TO-220AB (SOT78D) | |

6. Ordering information

| Table 3. Ordering in | formation | | | | | |
|----------------------|-----------|---|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BTA412Y-600B | TO-220AB | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 | SOT78D | | | |

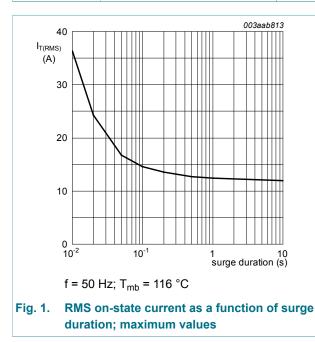
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7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | P | Min | Max | Unit |
|---------------------|--------------------------------------|---|---|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 116 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 12 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{Fig. 4}; \text{Fig. 5}$ | - | - | 140 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$ | - | - | 153 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | - | 98 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs | - | - | 100 | A/µs |
| I _{GM} | peak gate current | | | - | 2 | А |
| P _{G(AV)} | average gate power | over any 20 ms period | | - | 0.5 | W |
| T _{stg} | storage temperature | | | -40 | 150 | °C |
| Тj | junction temperature | | - | - | 150 | °C |



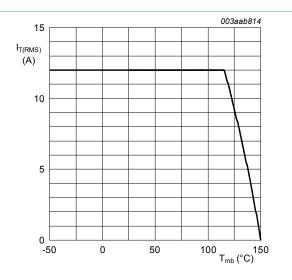
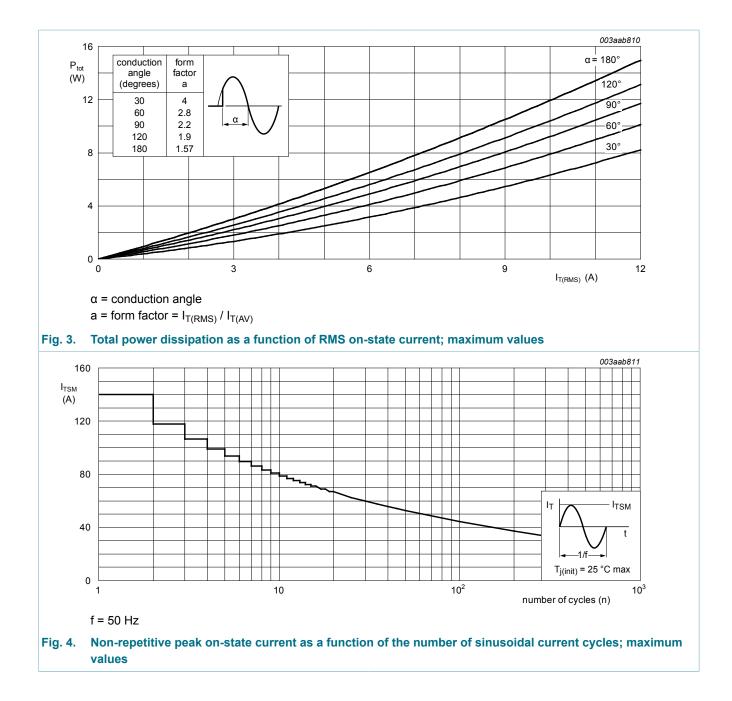


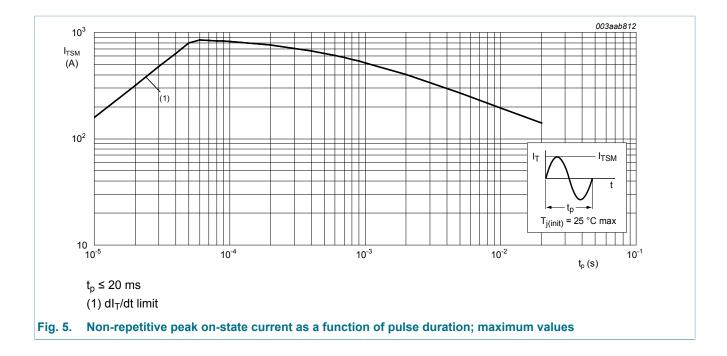
Fig. 2. RMS on-state current as a function of mounting base temperature; maximum values

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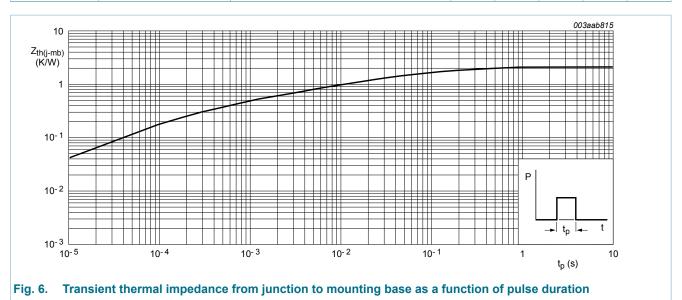
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8. Thermal characteristics

| Table 5. Th | ermal characteristics | | | | | |
|-----------------------|---|---------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | full cycle; <u>Fig. 6</u> | - | - | 2.1 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



9. Isolation characteristics

| Table 6. Isolation characteristics | | | | | | | | |
|------------------------------------|-----------------------|--|--|-----|-----|------|------|--|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit | |
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _{mb} = 25 °C | | - | - | 2500 | V | |
| C _{isol} | isolation capacitance | from main terminal 2 to external heatsink; f = 1 MHz; T _{mb} = 25 °C | | - | 10 | - | pF | |

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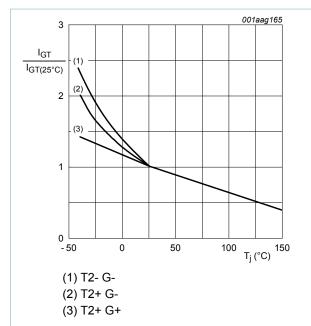
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10. Characteristics

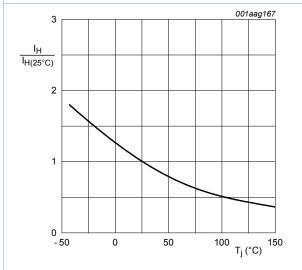
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------------------|---------------------------------------|---|------|-----|-----|------|
| Static chara | acteristics | | | | | |
| I _{GT} gate trigger cur | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | 2 | - | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | 2 | - | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | 2 | - | 50 | mA |
| IL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 60 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 90 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 60 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 60 | mA |
| V _T | on-state voltage | I _T = 18 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.3 | 1.5 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u> | - | 0.8 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 150 °C; <u>Fig. 11</u> | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| | | V _D = 600 V; T _j = 150 °C | - | 0.4 | 2 | mA |
| Dynamic ch | naracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 1000 | - | - | V/µs |
| | | V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 600 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 12 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit | 20 | - | - | A/ms |
| | | V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 12 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit | 8 | - | - | A/ms |

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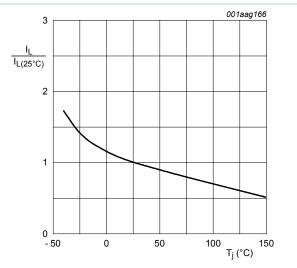
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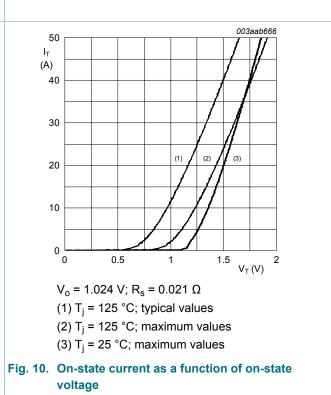








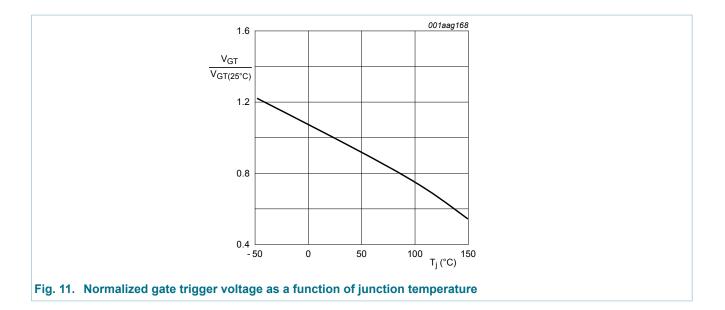




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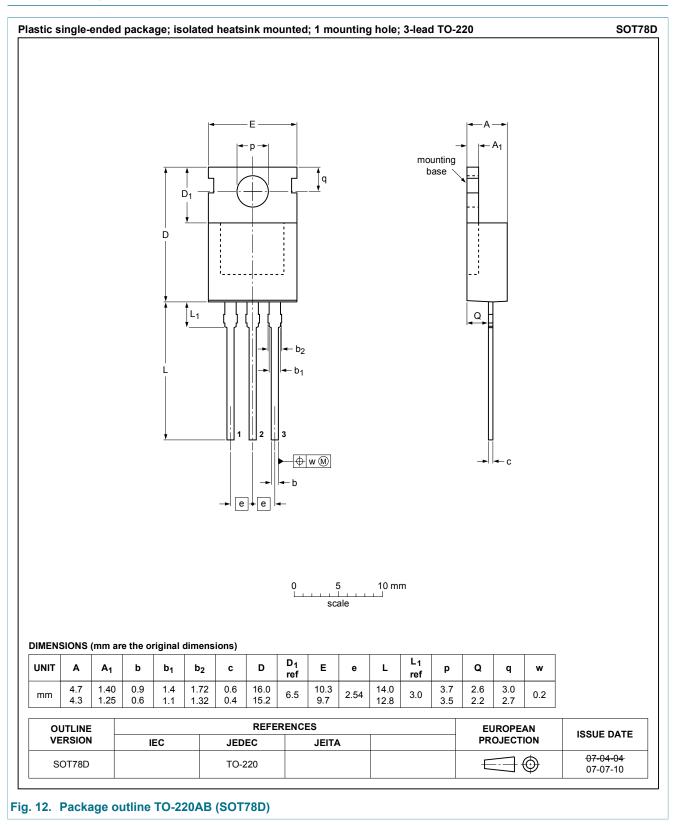
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11. Package outline



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|--------------------------------------|-------------------------------|---|
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13. Contents

| 1 | General description | 1 |
|------|---------------------------|----|
| 2 | Features and benefits | 1 |
| 3 | Applications | 1 |
| 4 | Quick reference data | 1 |
| 5 | Pinning information | 2 |
| 6 | Ordering information | 2 |
| 7 | Limiting values | 3 |
| 8 | Thermal characteristics | 6 |
| 9 | Isolation characteristics | 6 |
| 10 | Characteristics | 7 |
| 11 | Package outline | 10 |
| 12 | Legal information | 11 |
| 12.1 | Data sheet status | 11 |
| 12.2 | Definitions | 11 |
| 12.3 | Disclaimers | 11 |
| 12.4 | Trademarks | 12 |
| | | |

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